

Available on commercial versions Qualified per MIL-	<u>Qualified Levels</u> : JAN, JANTX, and JANTXV				
DESCRIPTION					
This Schottky barrier diode is metallurgically bonded and for high-reliability applications on "1N" prefixed numbers sealed and bonded into a DO-35 glass package.					
Important: For the latest information, visit our website http://www.mic	rosemi.com.				
FEATURES				DO-35 (DO-204AH)	
 JEDEC registered 1N5711-1, 1N5712-1, 1N6857-1, and ² Metallurgically bonded. 	IN6858-1 numb	ers.		Package	
• JAN, JANTX, JANTXV and commercial qualifications also	available per N	IIL-PRF-19500/	444 on	Also available in:	
"1N" numbers only.				📆 UB package	
(See Part Nomenclature for all available options).				(3-pin surface mount)	
RoHS compliant versions available (commercial grade on	HS compliant versions available (commercial grade only). (B, CC, CA)				
				(surface mount)	
APPLICATIONS / BEN	EEITO			<u>1N5711UR-1, 1N5712UR-1, 1N6857UR-1, and</u>	
 Low reverse leakage characteristics. Small size for high density mounting using flexible thru-ho ESD sensitive to Class 1. 	le leads (see pa	ackage illustratio	on).		
MAXIMUM RATINGS @ 25 °C unle	ss otherwise st	tated			
Parameters/Test Conditions	Symbol	Value	Unit		
Junction and Storage Temperature	T _J and T _{STG}	-65 to +150	°C		
Thermal Resistance, Junction-to-Lead	R _{OJL}	250	°C/W	MSC – Lawrence	
@ lead length = 0.375 inch (9.52 mm) from body				6 Lake Street,	
Average Rectified Output Current:				Lawrence, MA 01841 Tel: 1-800-446-1158 or	
1N5711 ⁽¹⁾ DSB2810, DSB5712, 1N5712 & 1N6858 ⁽²⁾		33 75	mA	(978) 620-2600	
1N6857 ⁽³⁾		150		Fax: (978) 689-0803	
Solder Temperature @ 10 s		260	°C	MSC – Ireland	
NOTES: 1. At $T_L = +130^{\circ}$ C and L = 0.375 inch, derate I_0 to 0 at +18 2. At $T_L = +110^{\circ}$ C and L = 0.375 inch, derate I_0 to 0 at +18 3. At $T_L = +70^{\circ}$ C and L = 0.375 inch, derate I_0 to 0 at +150	50°C.			Gort Road Business Park, Ennis, Co. Clare, Ireland Tel: +353 (0) 65 6840044 Fax: +353 (0) 65 6822298 Website: www.microsemi.com	
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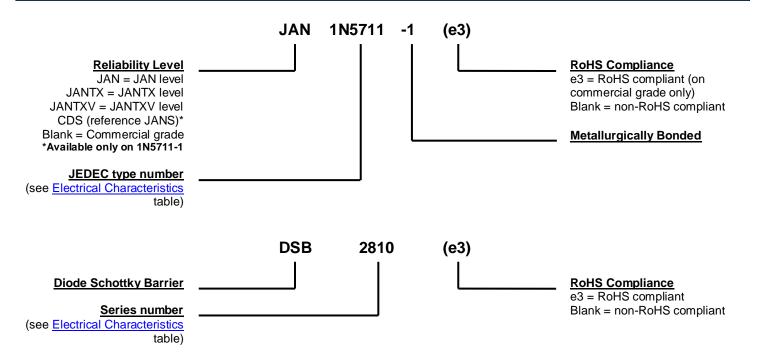


1N5711-1, 1N5712-1, 1N6857-1, and 1N6858-1; DSB2810 and DSB5712

MECHANICAL and PACKAGING

- CASE: Hermetically sealed glass package.
- TERMINALS: Tin/lead plated or RoHS compliant matte-tin (on commercial grade only) over copper clad steel. Solderable per MIL-STD-750, method 2026.
- POLARITY: Cathode indicated by band.
- MARKING: Part number.
- TAPE & REEL option: Standard per EIA-296. Consult factory for quantities.
- WEIGHT: Approximately 0.2 grams.
- See <u>Package Dimensions</u> on last page.

PART NOMENCLATURE



SYMBOLS & DEFINITIONS						
Symbol	Definition					
С	Capacitance: The capacitance in pF at a frequency of 1 MHz and specified voltage.					
f	frequency					
I _R	Reverse Current: The dc current flowing from the external circuit into the cathode terminal at the specified voltage V _R .					
Ιo	Average Rectified Output Current: The Output Current averaged over a full cycle with a 50 Hz or 60 Hz sine-wave input and a 180 degree conduction angle.					
t _{rr}	Reverse Recovery Time: The time interval between the instant the current passes through zero when changing from the forward direction to the reverse direction and a specified decay point after a peak reverse current occurs.					
V _(BR)	Breakdown Voltage: A voltage in the breakdown region.					
VF	Forward Voltage: A positive dc anode-cathode voltage the device will exhibit at a specified forward current.					
VR	Reverse Voltage: A positive dc cathode-anode voltage below the breakdown region.					
V _{RWM}	Working Peak Reverse Voltage: The peak voltage excluding all transient voltages (ref JESD282-B). Also sometimes known historically as PIV.					



1N5711-1, 1N5712-1, 1N6857-1, and 1N6858-1; DSB2810 and DSB5712

ELECTRICAL CHARACTERISTICS @ 25 °C unless otherwise noted							
TYPE NUMBER	MINIMUM BREAKDOWN VOLTAGE	MAXIMUM FORWARD VOLTAGE	MAXIMUM FORWARD VOLTAGE	WORKING PEAK REVERSE VOLTAGE	MAXIMUM REVERSE LEAKAGE CURRENT		$\begin{tabular}{lllllllllllllllllllllllllllllllllll$
	V _(BR) @ 10 µA	V _F @ 1 mA	V F @ I F	VRWM			С
	Volts	Volts	V @ mA	V (pk)	nA	Volts	pF
1N5711-1	70	0.41	1.0 @ 15	50	200	50	2.0
1N5712-1	20	0.41	1.0 @ 35	16	150	16	2.0
1N6857-1	20	0.35	0.75 @ 35	16	150	16	4.5
1N6858-1	70	0.36	0.65 @ 15	50	200	50	4.5
DSB2810	20	0.41	1.0 @ 35	16	100	15	2.0
DSB5712	20	0.41	1.0 @ 35	16	150	16	2.0



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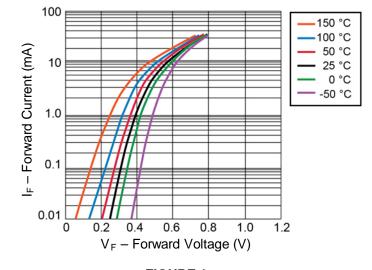


FIGURE 1 <u>I-V Curve showing typical Forward Voltage Variation</u> Temperature for the 1N5712-1, DSB5712 and DSB2810 Schottky Diodes

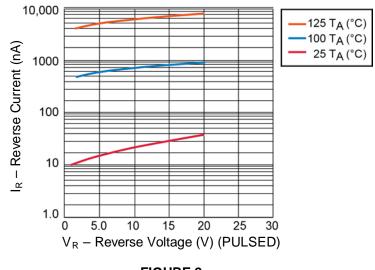
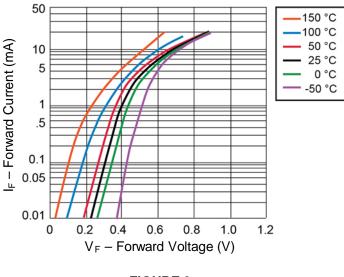


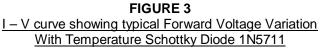
FIGURE 2 <u>1N5712-1, DSB5712 and DSB2810 Typical variation of Reverse</u> <u>Current (I_R) vs Reverse Voltage (V_R) at Various Temperatures</u>



1N5711-1, 1N5712-1, 1N6857-1, and 1N6858-1; DSB2810 and DSB5712

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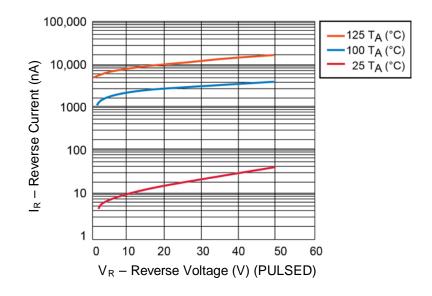


FIGURE 4 <u>1N5711 Typical Variation of Reverse Current (I_R) vs Reverse Voltage (V_R)</u> <u>at Various Temperatures</u>



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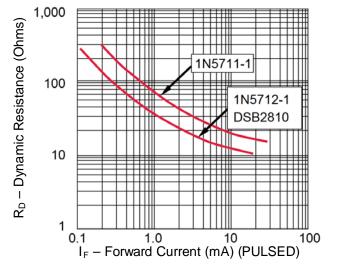
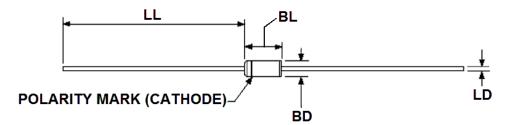


FIGURE 5 Typical Dynamic Resistance (R_D) vs Forward Current (I_F)



PACKAGE DIMENSIONS



NOTES:

- 1. Dimensions are in inches. Millimeters are given for information only.
- 2. Dimensions BL and LD includes all components of the diode periphery expect the section of the leads over which the diameter is controlled.
- 3. Dimension BD shall be measured at the largest diameter.
- 4. In accordance with ASME Y1.4M, diameters are equivalents to ϕx symbology.

Symbol	Inches		Millin	Notes	
	Min	Max	Min	Max	
BD	0.068	0.076	1.73	1.93	2,3
BL	0.125	0.170	3.18	4.32	2
LD	0.014	0.022	0.36	0.56	
LL	1.000	1.500	25.40	38.10	